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with microwave devices on a single chip with use some technological methods. This integration will get a system on a chip (SoC), that will provide economic benefits and will reduce the size of the system.

Keywords: microelectromechanical systems (MEMS), micromachined tunable capacitor, microwave monolithical integrated circuits (MMIC), varactor, radio frequency, varactor with variable dielectric, varactor with variable overlap area, varactor with variable gap

Keywords: arterial intima, endothelium, lipoprotein, LDL, atomic force microscopy, 3D model, finite-elemen modeling, tangential stress, normal stress, strain

Keywords: microelectromechanical systems (MEMS), selective laser sintering (SLS), titanium nickel (nitinol), shape memory effect (SME), drug delivery systems (DDS), tissue engineering matrix (scaffolds)

Keywords: multisensor microsystem, aroma recognition, sensor response dynamics, thin films, tin dioxide

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